



**TET ESTEL AS**  
ESTONIA

**April**  
**2017**

**Series**  
**TL233-400**

## Avalanche Press-Pack Thyristor Type TL233-400

Center amplifying gate

Guaranteed avalanche power dissipation in reverse direction

Designed for traction and industrial applications

Maximum mean on-state current	$I_{TAV}$	<b>400 A</b>				
Maximum repetitive peak off-state and reverse voltage	$U_{DRM}$ $U_{RRM}$	<b>600 ÷ 1100 V</b>				
Turn-off time	$t_q$	<b>80; 100; 125 <math>\mu</math>s</b>				
$U_{DRM}, U_{RRM}, V$	600	700	800	900	1000	1100
Voltage code	6	7	8	9	10	11
$T_{vj}, ^\circ C$	- 60 ÷ 140					

### MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	TL233-400	Conditions
$I_{TAV}$	Mean on-state current	A	400 690	$T_c=102^\circ C$ , $T_c=55^\circ C$ 180° half-sine wave, 50 Hz
$I_{TRMS}$	RMS on-state current	A	628	$T_c=102^\circ C$
$I_{TSM}$	Surge on-state current	kA	8,0 9,0	$T_{vj}=140^\circ C$ $T_{vj}=25^\circ C$ tp=10 ms $U_R=0$
$I^2t$	Limiting load integral	$kA^2s$	320 405	$T_{vj}=140^\circ C$ $T_{vj}=25^\circ C$
$U_{DRM}, U_{RRM}$	Repetitive peak off-state and reverse voltage	V	600÷1100	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz Gate open
$U_{DSM}, U_{RSM}$	Non-repetitive peak off-state and reverse voltage	V	660÷1210	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave tp=10 ms, Single pulse Gate open
(diT/dt) crit	Critical rate of rise of on-state current : non - repetitive repetitive	A/ $\mu$ s	250 125	$T_{vj}=140^\circ C$ ; $U_D=0,67 U_{DRM}$ , Gate pulse : 10V,5 $\Omega$ , 1 $\mu$ s rise time, 10 $\mu$ s
$U_{RGM}$	Peak reverse gate voltage	V	5	$T_j \min \leq T_{vj} \leq T_{jM}$
$P_{RSM}$	Surge reverse power dissipation	kW	40	$T_{vj}=140^\circ C$ ; tp = 10 $\mu$ s 180° half-sine wave
$T_{stg}$	Storage temperature	$^\circ C$	-60÷80	
$T_{vj}$	Junction temperature	$^\circ C$	-60÷140	

### CHARACTERISTICS

$U_{TM}$	Peak on-state voltage	V	2,2	$T_{vj}=25^\circ C$ , $I_{TM}=3,14 I_{TAV}$
$U_{T(TO)}$	Threshold voltage	V	1,2	$T_{vj}=140^\circ C$
$R_T$	On-state slope resistance	m $\Omega$	0,9	1,57 $I_{TAV} < I_T < 4,71 I_{TAV}$
$I_{DRM}$ $I_{RRM}$	Repetitive peak off-state and reverse current	mA	35 35	$T_{vj}=140^\circ C$ , $U_D = U_{DRM}$ $U_R = U_{RRM}$

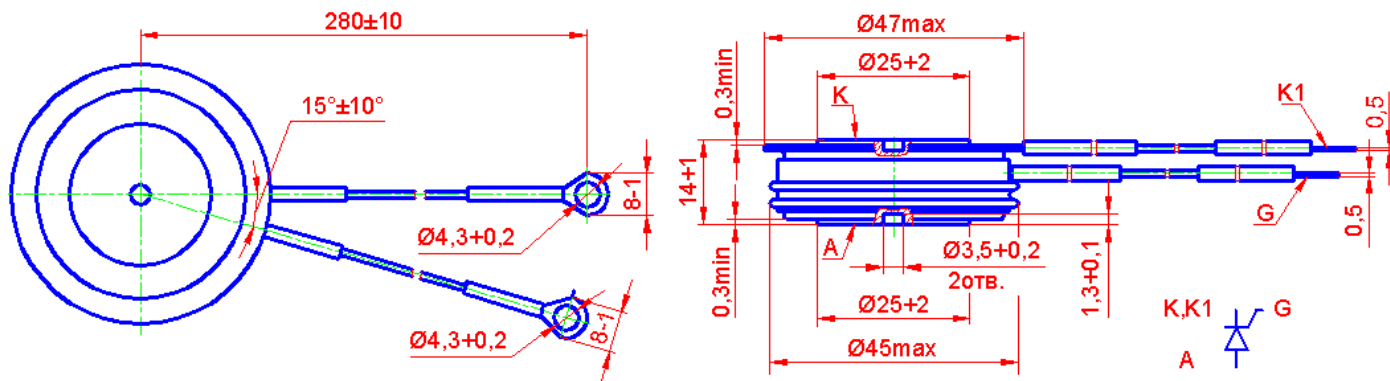
## CHARACTERISTICS

Symbols and parameters		Units	TL233-400	Conditions
$I_L$	Latching current	A	0,7	$T_{vj}=25^{\circ}\text{C}, U_D=12\text{V}$ Gate pulse : 10V, 5 $\Omega$ , 1 $\mu\text{s}$ rise time, 10 $\mu\text{s}$
$I_H$	Holding current	A	0,3	$T_{vj}=25^{\circ}\text{C}, U_D=12\text{V}$ , Gate open
$U_{GT}$	Gate trigger direct voltage	V	2,5 5,0	$T_{vj}=25^{\circ}\text{C}$ , $T_{vj}=-60^{\circ}\text{C}$ $U_D=12\text{V}$
$I_{GT}$	Gate trigger direct current	A	0,3 0,85	$T_{vj}=25^{\circ}\text{C}$ , $T_{vj}=-60^{\circ}\text{C}$
$U_{GD}$	Gate non-trigger direct voltage	V	0,4	$T_{vj}=140^{\circ}\text{C}$ , $U_D = 0,67 U_{DRM}$
$I_{GD}$	Gate non-trigger direct current	mA	6	Direct gate current
$t_{gd}$	Delay time	$\mu\text{s}$	1,6	$T_{vj}=25^{\circ}\text{C}, U_D=500\text{V}$ $I_{TM} = 400 \text{ A}$
$t_{gt}$	Turn-on time	$\mu\text{s}$	3,2	Gate pulse : 10V, 5 $\Omega$ , 1 $\mu\text{s}$ rise time, 10 $\mu\text{s}$
$t_q$	Turn-off time	$\mu\text{s}$	80÷125	$T_{vj}=140^{\circ}\text{C}$ , $I_{TM}=400 \text{ A}$ $di_R/dt = 10 \text{ A}/\mu\text{s}$ , $U_R=100\text{V}$ $U_D = 0,67 U_{DRM}$ $du_D/dt=50 \text{ V}/\mu\text{s}$
$Q_{rr}$	Recovered charge	$\mu\text{C}$	700	$T_{vj}=140^{\circ}\text{C}$ , $I_{TM}=400 \text{ A}$ $di_R/dt=10 \text{ A}/\mu\text{s}$ , $U_R=100\text{V}$
$t_{rr}$	Reverse recovery time	$\mu\text{s}$	6	
$I_{rrm}$	Peak reverse recovery current	A	230	$T_{vj}=140^{\circ}\text{C}$ , $U_D = 0,67 U_{DRM}$ Gate open
$(du_D/dt)_{crit}$	Critical rate of rise of off-state voltage	V/ $\mu\text{s}$	500 1000	
$R_{thjc}$	Thermal resistance junction to case	$^{\circ}\text{C}/\text{W}$	0,045	Direct current, double side cooled

## ORDERING

	TL	233	400	11	7	4	
	1	2	3	4	5	6	

- Avalanche thyristor.
- Design version.
- Mean on-state current, A.
- Voltage code (11=1100V).
- Critical rate of rise of off-state voltage ( $6 \geq 500 \text{ V}/\mu\text{s}$ ,  $7 \geq 1000 \text{ V}/\mu\text{s}$ ).
- Group of turn-off time ( $du_D/dt=50 \text{ V}/\mu\text{s}$ ,  $X2 \leq 125 \mu\text{s}$ ,  $4 \leq 100 \mu\text{s}$ ,  $B3 \leq 80 \mu\text{s}$ , 0-not limited).



Tightening torque : 9 ÷ 12 kN

Weight : 120 grams